

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

FDA24N50F

FEATURES

- With TO-3PN packaging
- · High speed switching
- Standard level gate drive
- · Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

APPLICATIONS

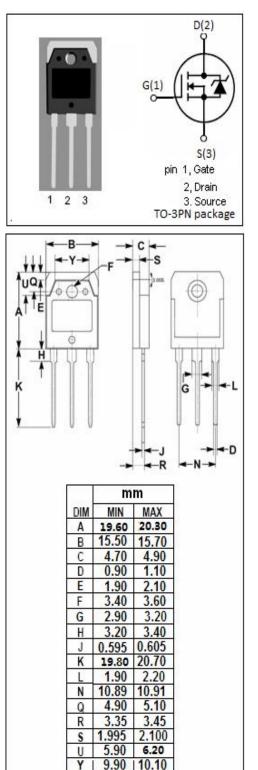
- Power supply
- Switching applications

SYMBOL PARAMETER VALUE UNIT Drain-Source Voltage 500 VDSS V V_{GSS} Gate-Source Voltage ± 30 V Drain Current-Continuous;Tc=25°C 24 I_{D} А 14 Tc=100℃ Drain Current-Single Pulsed 96 **I**DM А 270 P_{D} Total Dissipation W Ti **Operating Junction Temperature** -55~150 °C Tstg Storage Temperature -55~150 °C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.46	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C /W	

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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	500			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =10V; I _D =0.25mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =12A		0.16	0.2	Ω
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 500V; V _{GS} = 0V;Tc=25°C V _{DS} = 400V; V _{GS} = 0V;Tc=25°C			1 10	μA
V _{SDF}	Diode forward voltage	I _{SD} =24A, V _{GS} = 0 V			1.4	V

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